



**DACO SEMICONDUCTOR CO., LTD.**

**MBR60020CT(R)L**

## LOW VF SCHOTTKY DIODE MODULE TYPE 600A

### Features

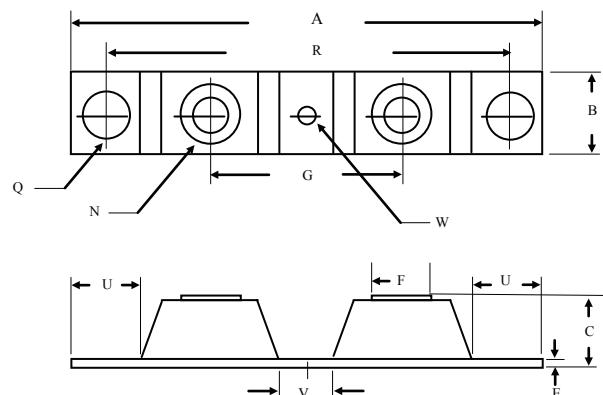
High Surge Capability

**600Amp Rectifier  
20 Volts**

### Maximum Ratings

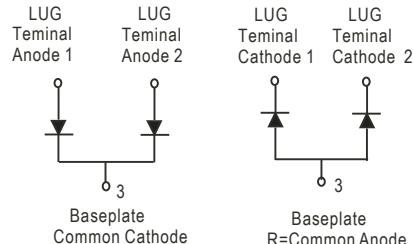
Operating Temperature: -40 °C to +100 °C  
Storage Temperature: -40 °C to +150 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBR60020CT(R)L	20V	14V	20V



### Electrical Characteristics @ 25 °C Unless Otherwise Specified

Average Forward Current (Per pkg)	I <sub>F(AV)</sub>	600A	TC=100°C
Peak Forward Surge Current (Per leg)	I <sub>FSM</sub>	4000A	8.3ms, half sine
Maximum Instantaneous Forward Voltage (Per leg)	V <sub>F</sub>	0.58V	I <sub>FM</sub> =300A; TJ=25°C
Maximum Instantaneous Reverse Current At Rated DC Blocking Voltage (Per leg)	I <sub>R</sub>	3mA	TJ= 25 °C
		250mA	TJ = 100 °C
Maximum Thermal Resistance Junction To Case (Per leg)	R <sub>θ j c</sub>	0.28 °C/W	



DIM	Inches		Millimeters	
	Min	Max	Min	Max
A	-----	3.630	-----	92.40
B	0.700	0.800	17.78	20.32
C	-----	0.650	-----	16.51
E	0.130	0.141	3.30	3.60
F	0.482	0.490	12.25	12.45
G	1.368	BSC	34.75	BSC
N	1/4-20 UNC FULL			
Q	0.275	0.290	6.99	7.37
R	3.150	BSC	80.01	BSC
U	0.600	-----	15.24	-----
V	0.312	0.370	7.92	9.40
W	0.180	0.195	4.57	4.95

#### NOTE :

- (1) Pulse Test: Pulse Width 300  $\mu$  sec. Duty Cycle < 2%



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Figure .1-Typical Forward Characteristics

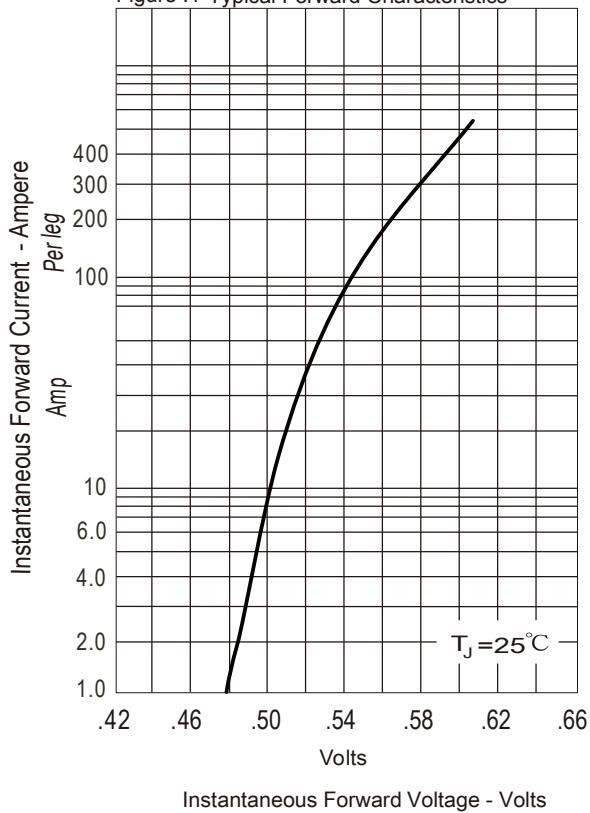


Figure .2- Forward Derating Curve

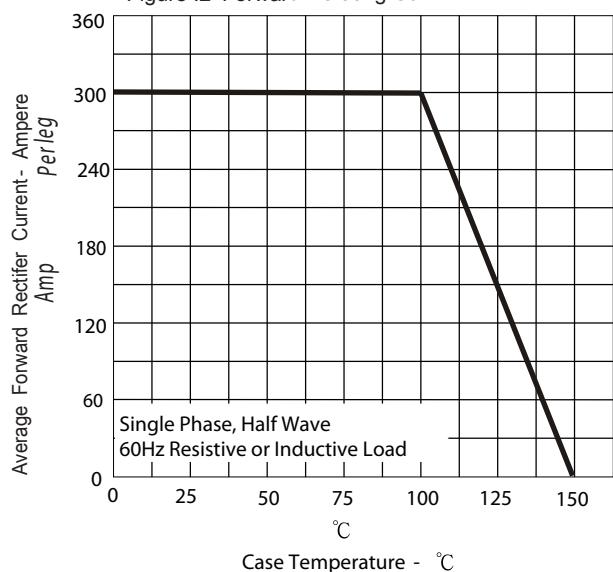


Figure .3- Peak Forward Surge Current

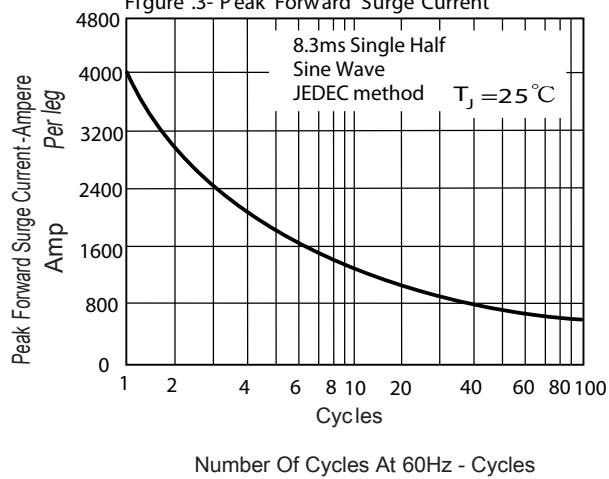


Figure .4- Typical Reverse Characteristics

